SIC

6H-SiC:N

490 μm, 5·10¹⁸ cm⁻³ SIC1,2

460 μm, 2·10¹⁸ cm⁻³ SIC3

(100) GaAs:Sn, 300 μm 2·10¹⁸ cm⁻³ GAS1 4·10¹⁶ cm⁻³ GAS2

GAS

(111)
GaAs:Te, 300 μm
2·10¹⁸ cm⁻³

GAT

GAE
(100)
GaAs:Te, 300 μm
2·10¹⁸ cm⁻³

GaAs:Te, 6 μm, 3,9·10¹⁵ cm⁻³ GAE1 3,5·10¹⁵ cm⁻³ GAE2 5·10¹⁵ cm⁻³ GAE3 GAB

(100)

GaAs:Te, 300 μm $2 \cdot 10^{18}$ cm⁻³

GaAs:Te, 1 μm, $8 \cdot 10^{16}$ cm⁻³

GaAs:Te, 2 μm, $7 \cdot 10^{15}$ cm⁻³